

HF WIDEBAND TRANSISTORS

The BFW17 is NPN multi-emitter transistor in a TO-39 metal envolope, with the collector connected to the case. The transistor has extremely good intermodulation properties and a high power gain.

It is primarily intended for:

NPN BFW17

- •Final and driver stages of channel and band aerial amplifiers with high outpout power for bands I , II , III (40-230 MHz).
- •Final stage of the wideband vertical amplifier in high speed oscilloscopes. Compliance to RoHS.

ABSOLUTE MAXIMUM RATINGS

Symbol	Rat	tings	Value	Unit
V _{CEO}	Collector-Emitter Voltage	$I_B = 0$	25	V
V _{CBOM}	Collector-Base Voltage (open emitter; peak value)	I _E = 0	40	V
V _{EBO}	Emitter-Base Voltage	$I_C = 0$	2	V
V _{CERM}	Collector-Emitter Voltage	R _{BE} <=50Ω	40	V
Ic	Collector Current		150	mA
Ісм	Collector Peak Current		300	mA
Pt	Total Power Dissipation	@ T _C = 125°	1.5	W
TJ	Junction Temperature		200	°C
T _{Stg}	Storage Temperature		-65 to +200	°C

THERMAL CHARACTERISTICS

Symbol	Ratings	Value	Unit
R_{thJa}	Thermal Resistance, Junction to Ambient	250	K/W
R _{thJmb}	Thermal Resistance, Junction to Mounting Base	50	K/W
R _{thJmb-h}	Thermal Resistance, Junction to Mounting Base to heatsink	1.2	K/W



ELECTRICAL CHARACTERISTICS

TC=25°C unless otherwise noted

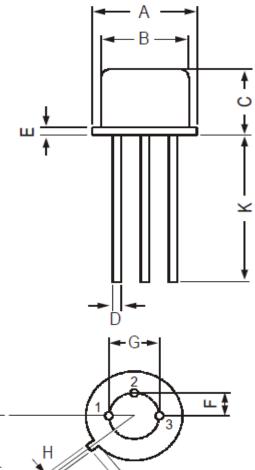
Symbol	Ratings	Test Condition(s)	Min	Тур	Max	Unit
I _{CB0}	Collector Cutoff Current	I _E =0, V _{CB} =20 V, T _J =150°C	-	-	20	μA
h _{FE}	DC Current Gain	I _C =50 m A, V _{CE} =5.0 V I _C =150 mA, V _{CE} =5.0 V	25 25	-	-	_
f⊤	Transition frequency	V _{CE} =15 V, I _C =150 mA f=500 MHz	-	1.1	-	GHz
Cc	Collector capacitance at f=1MHz	$I_{E}=I_{e}=0, V_{CB}=15 V$	-	-	4	5F
Cre	Feedback capacitance at f=1MHz	I _C = 10 mA, V _{CE} =15 V T _{amb} = 25°C	-	1.7	-	pF
G_P	Power gain (not neutralized) f= 200 MHz	I_C = 70 mA V_{CE} =18 V T_{amb} = 25°C	-	16	-	dB



MECHANICAL DATA CASE TO-39

DIMENSIONS (mm)		
	min	max
Α	8.50	9.39
В	7.74	8.50
С	6.09	6.60
D	0.40	0.53
Е	-	0.88
F	2.41	2.66
G	4.82	5.33
Н	0.71	0.86
J	0.73	1.02
K	12.70	-
L	42°	48°

Emitter	Pin 1 :
Base	Pin 2 :
Collector	Pin 3 :
Collector	Case :





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www.comsetsemi.com

info@comsetsemi.com